NSN 5961-01-353-6219

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View Online at https://aerobasegroup.com/nsn/5961-01-353-6219 **Inclosure Material:** Plastic or ceramic **Overall Length:** 0.125 inches **Overall Height:** 0.060 inches **Overall Width:** 0.062 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to base voltage/static/emitter open and 45.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0